1.8V / 2.5V Differential 2:1 Mux Input to 1:6 CML Clock/Data Fanout Buffer/Translator

Multi-Level Inputs w/ Internal Termination Description

The NB7V585M is a differential 1-to-6 CML clock/data distribution chip featuring a 2:1 Clock/Data input multiplexer with an input select pin. The INx/INx inputs incorporate internal 50 Ω termination resistors and will accept LVPECL, CML, or LVDS logic levels (see Figure 9). The NB7V585M produces six identical output copies of clock or data operating up to 6 GHz or 10 Gb/s, respectively. As such, NB7V585M is ideal for SONET, GigE, Fiber Channel, Backplane and other clock/data distribution applications. The 16 mA differential CML output structure provides matching internal 50 Ω source terminations, 400 mV output swings when externally terminated with a 50 Ω resistor to V_{CC} (see Figure 14) and is optimized for low skew and minimal jitter. The NB7V585M is powered with either 1.8 V or 2.5 V supply and is offered in a low profile 5x5 mm 32-pin QFN package.

Application notes, models, and support documentation are available at www.onsemi.com.

The NB7V585M is a member of the GigaComm[™] family of high performance clock products.

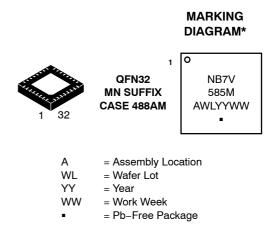
Features

- Maximum Input Data Rate > 10 Gb/s
- Data Dependent Jitter < 10 ps
- Maximum Input Clock Frequency > 6 GHz
- Random Clock Jitter < 0.8 ps RMS, Max
- Low Skew 1:6 CML Outputs, 20 ps Max
- 2:1 Multi-Level Mux Inputs
- 175 ps Typical Propagation Delay
- 50 ps Typical Rise and Fall Times
- Differential CML Outputs, 330 mV Peak-to-Peak, Typical
- Operating Range: $V_{CC} = 1.71$ V to 1.89 V
- Internal 50 Ω Input Termination Resistors
- V_{REFAC} Reference Output
- QFN32 Package, 5 mm x 5 mm
- -40°C to +85°C Ambient Operating Temperature
- These are Pb-Free Devices



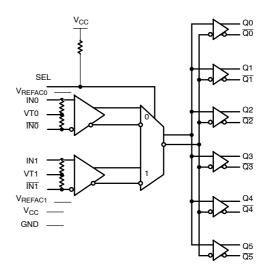
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*For additional marking information, refer to Application Note AND8002/D.

SIMPLIFIED LOGIC DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

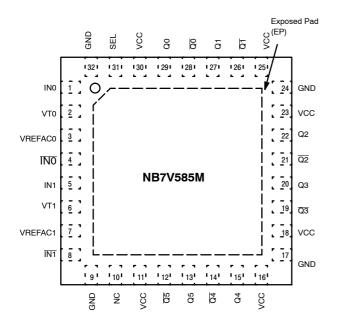


Figure 1. 32-Lead QFN Pinout (Top View)

Table 2. PIN DESCRIPTION

I/O Pin Name Description INO. INO LVPECL, CML, 1.4 Non-inverted, Inverted, Differential Inputs 5,8 IN1, IN1 LVDS Input 2,6 VT0, VT1 Internal 100 Ω Center-tapped Termination Pin for IN0/IN0 and IN1/IN1 LVTTL/LVCMOS 31 SEL Input Select pin; LOW for IN0 Inputs, HIGH for IN1 Inputs; defaults HIGH when left open Input NC 10 No Connect _ 11, 16, 18 VCC Positive Supply Voltage. 23, 25, 30 29, 28 Q0, Q0 CML Output Non-inverted, Inverted Differential Outputs (Note 1). 27, 26 Q1, Q1 Q2, Q2 Non-inverted, Inverted Differential Outputs (Note 1). 22, 21 CML Output 20, 19 Q3. Q3 15, 14 Q4, Q4 CML Output Non-inverted, Inverted Differential Outputs (Note 1). Q5, Q5 13, 12 9, 17 GND Negative Supply Voltage, connected to Ground 24, 32 З VREFAC0 _ Output Voltage Reference for Capacitor-Coupled Inputs, only 7 VREFAC1 The Exposed Pad (EP) on the QFN-32 package bottom is thermally connected to the EP die for improved heat transfer out of package. The exposed pad must be attached to a heat-sinking conduit. The pad is electrically connected to the die, and must be electrically and thermally connected to GND on the PC board.

 In the differential configuration when the input termination pins (VT0, VT1) are connected to a common termination voltage or left open, and if no signal is applied on INn/INn input, then, the device will be susceptible to self-oscillation. Qn/Qn outputs have internal 50 Ω source termination resistors.

2. All V_{CC} and GND pins must be externally connected to a power supply for proper operation.

1

Table 1. INPUT SELECT FUNCTION TABLE

CLK Input Selected

IN0

IN1

*Defaults HIGH when left open.

SEL*

0

Table 3. ATTRIBUTES

Characte	Value			
ESD Protection Human Body Model Machine Model		> 4 kV > 200 V		
Input Pullup Resistor (R _{PU})		75 kΩ		
Moisture Sensitivity (Note 3)		Level 1		
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
Transistor Count	308			
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test				

3. For additional information, see Application Note AND8003/D.

Table 4. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Power Supply	GND = 0 V		3.0	V
V _{IO}	Input/Output Voltage	GND = 0 V	$-0.5 \leq V_{IO} \leq V_{CC} + 0.5$	-0.5 to V _{CC} + 0.5	V
V _{INPP}	Differential Input Voltage IN _x - IN _x			1.89	V
I _{IN}	Input Current Through R_T (50 Ω Resistor)			±40	mA
I _{OUT}	Output Current	Continuous Surge		34 40	mA
IVFREFAC	V _{REFAC} Sink/Source Current			±1.5	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient) (Note 4)	0 lfpm 500 lfpm	QFN-32 QFN-32	31 27	°C/W °C/W
θJC	Thermal Resistance (Junction-to-Case) (Note 4)	Standard Board	QFN-32	12	°C/W
T _{sol}	Wave Solder Pb-Free			265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
4. JEDEC standard multilayer board – 2S2P (2 signal, 2 power) with 8 filled thermal vias under exposed pad.

Symbol	Characteristic	Min	Тур	Max	Unit
POWER	SUPPLY CURRENT				
I _{CC}	Power Supply Current (Inputs and Outputs Open) $$V_{CC}$$ = 2.65 V $$V_{CC}$$ = 1.89 V		235 210	260	mA
CML OUT	rPUTS (Note 6)				<u>. </u>
V _{OH}	Output HIGH Voltage $$V_{CC}$$ = 2.5 V $$V_{CC}$$ = 1.8 V	V _{CC} – 40 2460 1760	V _{CC} – 20 2480 1780	V _{CC} 2500 1800	mV
V _{OL}	Output LOW Voltage $V_{CC} = 2.5 V$ $V_{CC} = 1.8 V$	V _{CC} – 500 2000 1300	V _{CC} – 400 2100 1400	V _{CC} – 275 2200 1500	mV
DIFFERE	NTIAL INPUTS DRIVEN SINGLE-ENDED (Note 7) (Figure 6)				-
V _{th}	Input Threshold Reference Voltage Range (Note 8)	1050		V _{CC} – 100	mV
V _{IH}	Single-Ended Input HIGH Voltage	V _{th} + 100		V _{CC}	mV
V _{IL}	Single-Ended Input LOW Voltage	GND		V _{th} – 100	mV
V _{ISE}	Single-Ended Input Voltage (V _{IH} - V _{IL})	200		1200	mV
V _{REFAC}					
V _{REFAC}	Output Reference Voltage @ 100 μA for Capacitor – Coupled Inputs, Only	V _{CC} - 625	V _{CC} – 500	V _{CC} – 400	mV
DIFFERE	NTIAL INPUTS DRIVEN DIFFERENTIALLY (Note 9) (Figures 4 and	l 7)			
V _{IHD}	Differential Input HIGH Voltage (IN, IN)	1100		V _{CC}	mV
V _{ILD}	Differential Input LOW Voltage (IN, IN)	GND		V _{CC} – 100	mV
V _{ID}	Differential Input Voltage (IN, IN) (V _{IHD} - V _{ILD})	100		1200	mV
V _{CMR}	Input Common Mode Range (Differential Configuration, Note 10) (Figure 9)	1050		V _{CC} – 50	mV
I _{IH}	Input HIGH Current IN/IN (VTO / VT1 Open)	-150		150	μA
IIL	Input LOW Current IN/IN (VTO / VT1 Open)	-150		150	μA
CONTRO	LINPUT (SEL Pin)				
V _{IH}	Input HIGH Voltage for Control Pin	V _{CC} x 0.65		V _{CC}	mV
V _{IL}	Input LOW Voltage for Control Pin	GND		V _{CC} x 0.35	mV
I _{IH}	Input HIGH Current	-150	20	+150	μΑ
IIL	Input LOW Current	-150	5	+150	μA
TERMINA	TION RESISTORS				
R _{TIN}	Internal Input Termination Resistor (Measured from INx to VTx)	45	50	55	Ω
R _{TOUT}	Internal Output Termination Resistor	45	50	55	Ω

board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

5. Input and output parameters vary 1:1 with V_{CC} .

6. CML outputs (Qn/Qn) have internal 50 Ω source termination resistors and must be externally terminated with 50 Ω to V_{CCO} for proper operation.

V_{th}, V_{IH}, V_{IL} and V_{ISE} parameters must be complied with simultaneously.
 V_{th} is applied to the complementary input when operating in single–ended mode.

V_{III} V_{ILD}, V_{ILD}, V_{ID} and V_{CMR} parameters must be complied with simultaneously.
 V_{CMR} min varies 1:1 with GND, V_{CMR} max varies 1:1 with V_{CC}. The V_{CMR} range is referenced to the most positive side of the differential input signal.

Symbol	Characteristic	Min	Тур	Max	Unit
f _{MAX}	Maximum Input Clock Frequency, $V_{OUTPP} \ge 200 \text{ mV}$	6.0	7.0		GHz
f _{DATAMAX}	Maximum Operating Input Data Rate (PRBS23)	10			Gbps
V _{OUTPP}	Output Voltage Amplitude (See Figures 4, Note 15) $$f_{in} \le 4.0~\text{GHz}$ $f_{in} \le 6.0~\text{GHz}$$	250 200	400 325		mV
t _{PLH} , t _{PHL}	$\begin{array}{llllllllllllllllllllllllllllllllllll$	125	175 200	250 300	ps
t _{PLH} TC	Propagation Delay Temperature Coefficient		100		fs/°C
t _{SKEW}	Output – Output Skew (Within Device) (Note 12) Device – Device Skew (t _{pd} Max – t _{pdmin})			30 50	ps
t _{DC}	Output Clock Duty Cycle (Reference Duty Cycle = 50%) $~f_{in} \leq 4.0~\text{GHz}$	45	50	55	%
t _{JITTER}	$ \begin{array}{ll} \mbox{Output Random Jitter (RJ) (Note 13)} & f_{in} \leq 6.0 \mbox{ GHz} \\ \mbox{Deterministic Jitter (DJ) (Note 14)} & f_{in} \leq 10 \mbox{ Gbps} \end{array} $		0.2	0.8 10	ps rms ps pk–pk
V _{INPP}	Input Voltage Swing (Differential Configuration) (Note 15)	100		1200	mV
t _r , t _f	Output Rise/Fall Times @ 1 GHz (20% – 80%) $Q_n, \overline{Q_n}$		50	65	ps

Table 6. AC CHARACTERISTICS V _{CC} = 1.8 V \pm 5% or 2.5 V \pm 5%	%, GND = 0 V, $T_A = -40^{\circ}C$ to $85^{\circ}C$ (Note 11)
--	---

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

Measured using a 400 mV source, 50% duty cycle clock source. All outputs must be loaded with external 50 Ω to V_{CC}. Input edge rates 40 ps (20% – 80%).

12. Skew is measured between outputs under identical transitions and conditions. Duty cycle skew is defined only for differential operation when the delays are measured from cross-point of the inputs to the crosspoint of the outputs.

13. Additive RMS jitter with 50% duty cycle clock signal.

14. Additive Peak-to-Peak data dependent jitter with input NRZ data at PRBS23.

15. Input and output voltage swing is a single-ended measurement operating in differential mode.

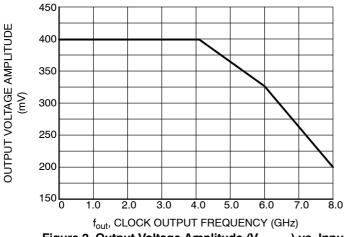


Figure 2. Output Voltage Amplitude (V_{OUTPP}) vs. Input Frequency (f_{in}) at Ambient Temperature (Typical)

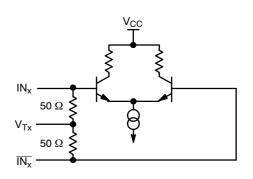
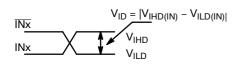
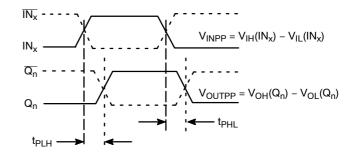


Figure 3. Input Structure









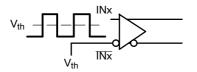
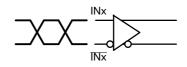


Figure 6. Differential Input Driven Single-Ended





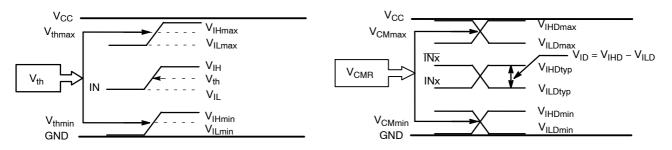




Figure 9. V_{CMR} Diagram

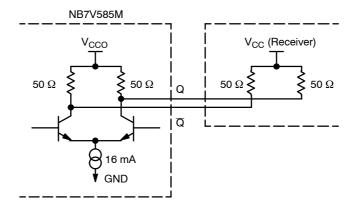
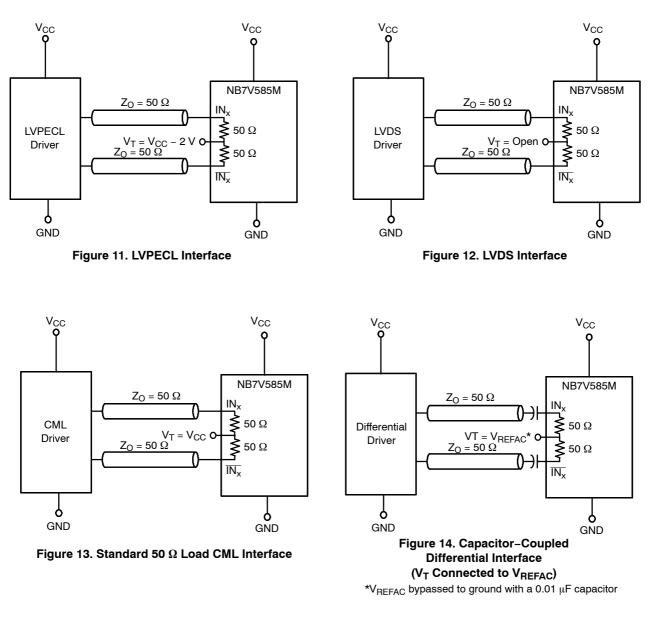


Figure 10. Typical CML Output Structure and Termination



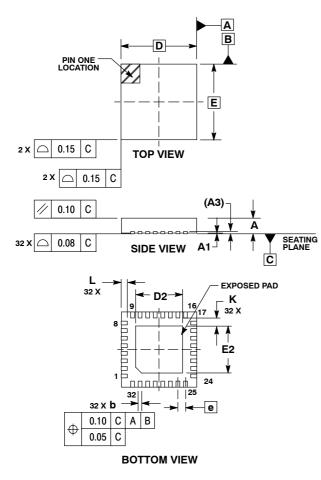
ORDERING INFORMATION

Device	Package	Shipping [†]
NB7V585MMNG	QFN32 (Pb-Free)	74 Units / Rail
NB7V585MMNR4G	QFN32 (Pb-Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

QFN32 5*5*1 0.5 P CASE 488AM-01 **ISSUE O**

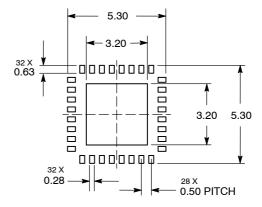


NOTES 1. DIMENSIONS AND TOLERANCING PER

- ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. 2.
- CONTROLLING DIMENSION: MILLINE TERS. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 MM TERMINAL COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS. З.
- 4.

	MILLIMETERS			
DIM	MIN NOM MA			
Α	0.800	0.900	1.000	
A1	0.000	0.025	0.050	
A3	0.200 REF			
b	0.180	0.250	0.300	
D	5.00 BSC			
D2	2.950	3.100	3.250	
Е	5.00 BSC			
E2	2.950	3.100	3.250	
е	0.500 BSC			
κ	0.200			
L	0.300	0.400	0.500	

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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